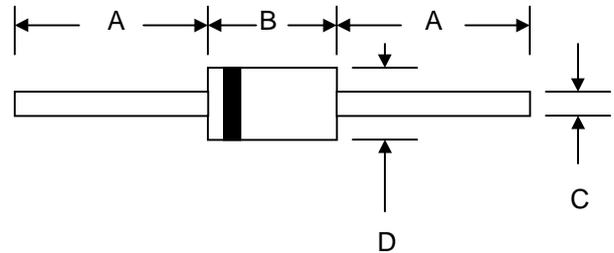




2.5A SILICON RECTIFIER

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability



Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.40 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version**

DO-15		
Dim	Min	Max
A	24.5	—
B	5.50	7.62
C	0.60	0.80
D	2.60	3.60
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	RL251	RL252	RL253	RL254	RL255	RL256	RL257	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>								
Working Peak Reverse Voltage	V <sub>RWM</sub>	50	100	200	400	600	800	1000	V
DC Blocking Voltage	V <sub>R</sub>								
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1)	I <sub>O</sub>	2.5							A
@T <sub>A</sub> = 75°C									
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	70							A
Forward Voltage	V <sub>FM</sub>	1.0							V
@I <sub>F</sub> = 2.5A									
Peak Reverse Current	I <sub>RM</sub>	5.0							μA
@T <sub>A</sub> = 25°C									
At Rated DC Blocking Voltage		50							
@T <sub>A</sub> = 100°C									
Typical Junction Capacitance (Note 2)	C <sub>j</sub>	20							pF
Typical Thermal Resistance Junction to Ambient (Note 1)	R <sub>θJA</sub>	40							K/W
Operating Temperature Range	T <sub>j</sub>	-65 to +150							°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150							°C

\*Glass passivated forms are available upon request

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case  
2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.

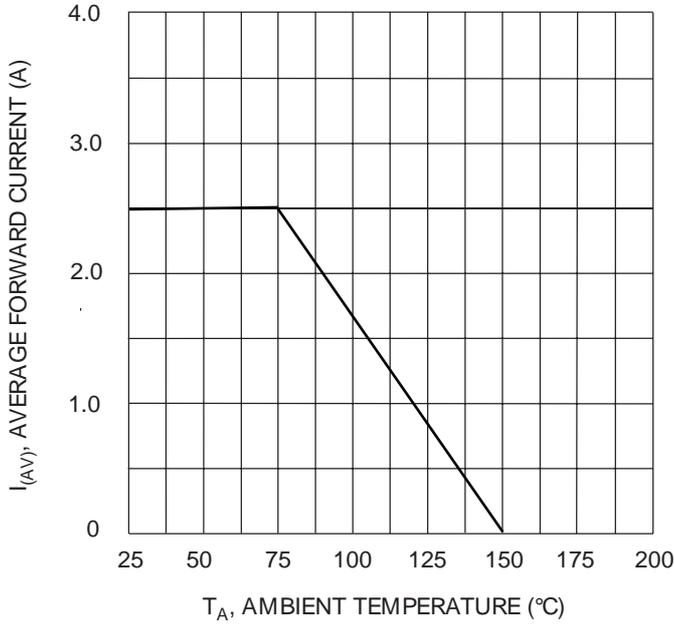


Fig. 1 Forward Current Derating Curve

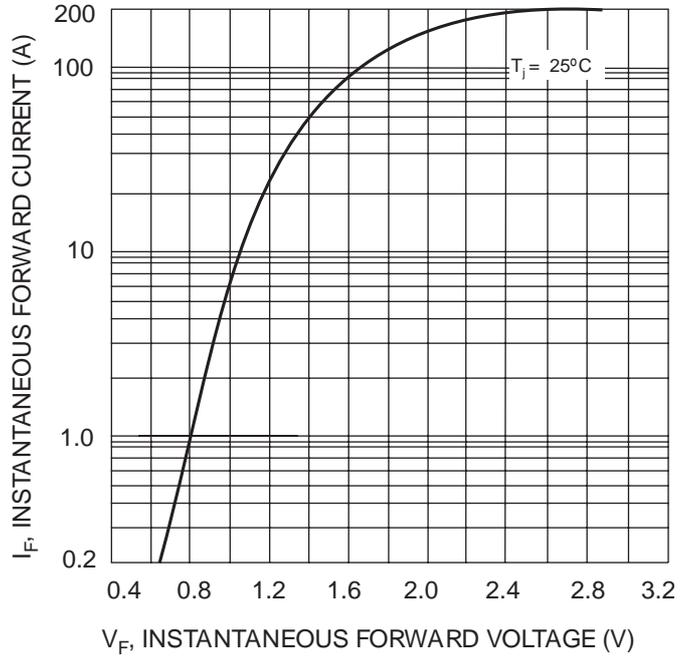


Fig. 2 Typical Forward Characteristics

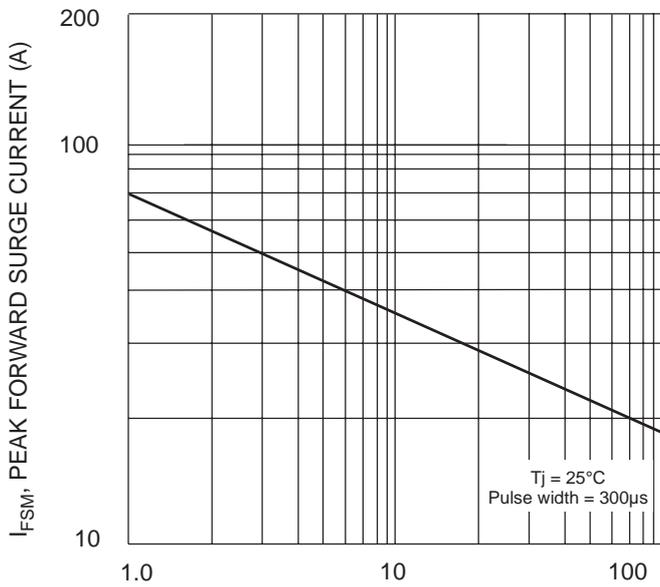


Fig. 3 Maximum Non-Repetitive Surge Current

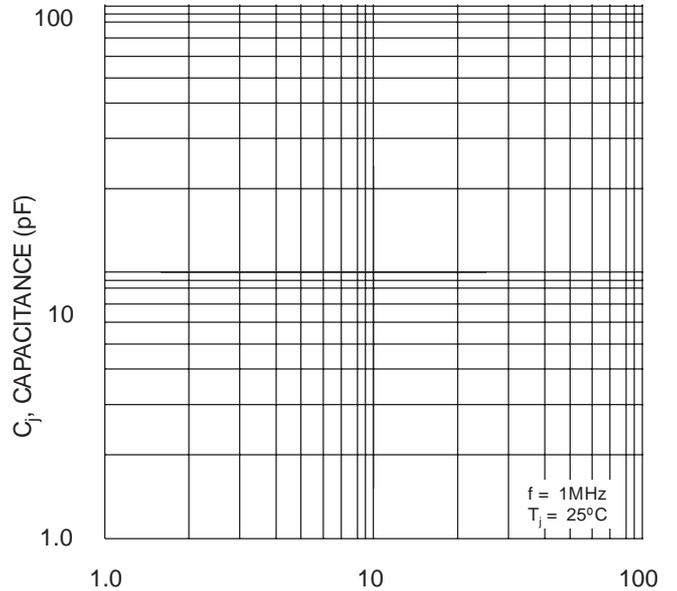


Fig. 4 Typical Junction Capacitance